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BLF8G20LS-200V

Power LDMOS transistor

AMPLEON

Rev. 5 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

200 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 1800 MHz to 2000 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit.

Test signal	f	I _{Dq}	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1805 to 1880	1600	28	55	17.5	33	-30 [1]

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Decoupling leads to enable improved video bandwidth (80 MHz typical)
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for W-CDMA base stations and multi carrier applications in the 1800 MHz to 2000 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	drain		4	1 4 5
2	gate		4 5	1, 4, 5
3	source	<u>[1]</u>		2
4,5	video decoupling			3
6	n.c.			aaa-003884
7	n.c.		2	

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	e number Package			
	Name	Description	Version	
BLF8G20LS-200V	-	earless flanged LDMOST ceramic package; 6 leads	SOT1120B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage			-	65	V
V_{GS}	gate-source voltage			-0.5	+13	V
T _{stg}	storage temperature			-65	+150	°C
T _j	junction temperature			-	200	°C
T _{case}	case temperature		<u>[1]</u>	-	150	°C

^[1] Continuous use at maximum temperature will affect MTTF

5. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
T _{case}	case temperature		-40	+125	°C

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 55 W	0.27	K/W

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7. Characteristics

Table 7. DC characteristics

 $T_i = 25$ °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.5 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 270 mA	1.5	1.9	2.3	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 1.6 A	1.7	2.1	2.5	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	4.2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	-	50.6	-	Α
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	420	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 13.5 A	-	19.6	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 9.45 A$	-	0.057	-	Ω

Table 8. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1600 mA; T_{case} = 25 °C; unless otherwise specified; in a production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 55 W$	16.3	17.5	19.2	dB
η_{D}	drain efficiency	$P_{L(AV)} = 55 W$	29	33	-	%
RLin	input return loss	$P_{L(AV)} = 55 W$	-	-15	-7	dB
ACPR	adjacent channel power ratio	$P_{L(AV)} = 55 W$	-	-30	-26	dBc

8. Test information

8.1 Ruggedness in class-AB operation

The BLF8G20LS-200V is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dg} = 1600 mA; P_L = 200 W (CW); f = 1805 MHz.

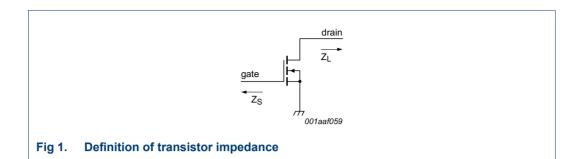
8.2 Impedance information

Table 9. Typical impedance

Measured load-pull data; $I_{Dq} = 1600 \text{ mA}$; $V_{DS} = 28 \text{ V}$.

f	Z _S ^[1]	Z _L [1]
(MHz)	(Ω)	(Ω)
1805	1.01 – j3.66	1.04 – j2.44
1843	1.12 – j3.97	1.04 – j2.44
1880	1.37 – j4.20	1.04 – j2.44

^[1] Z_S and Z_L defined in Figure 1.



8.3 Test circuit

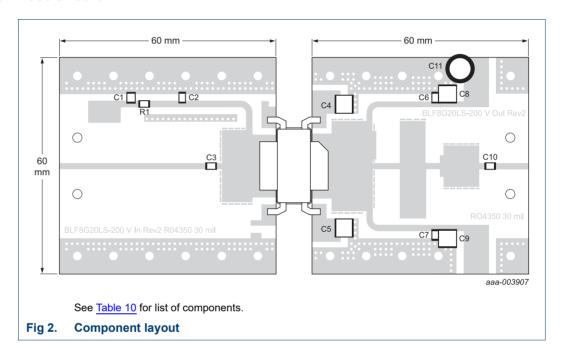


Table 10. List of components

See Figure 2 for component layout.

The used PCB material is Rogers RO4350B with a thickness of 0.76 mm.

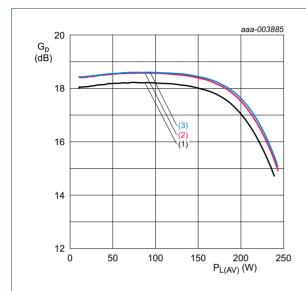
Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	4.7 μF	11 Murata
C2, C3	multilayer ceramic chip capacitor	20 pF	ATC100B
C4, C5	multilayer ceramic chip capacitor	4.7 μF	3 TDK
C6, C7	multilayer ceramic chip capacitor	8.2 pF	4 ATC800B
C8, C9	multilayer ceramic chip capacitor	4.7 μF	3 TDK
C10	multilayer ceramic chip capacitor	20 pF	4 ATC800B
C11	electrolytic capacitor	470 μF, 63 V	
R1	chip resistor	4.7 Ω	1206

- [1] Murata or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] TDK or capacitor of same quality.
- [4] American Technical Ceramics type 800B or capacitor of same quality.

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8.4 Graphical data

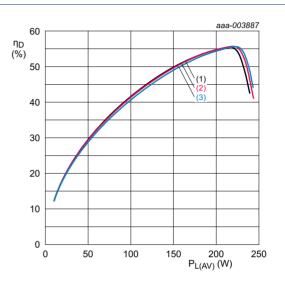
8.4.1 1-Tone CW



 V_{DS} = 28 V; I_{Dq} = 1600 mA.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 3. Power gain as a function of average output power; typical values

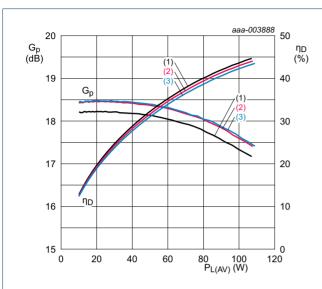


 V_{DS} = 28 V; I_{Dq} = 1600 mA.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 4. Drain efficiency as a function of average output power; typical values

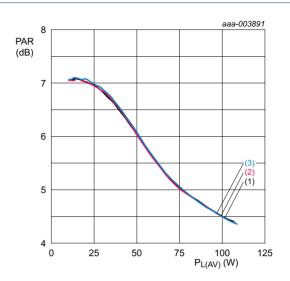
8.4.2 1-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 1600 mA; PAR = 7.2 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

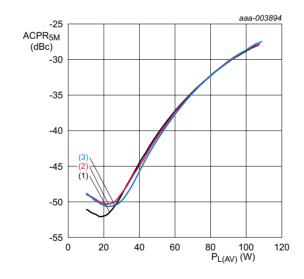
Fig 5. Power gain and drain efficiency as function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 1600 mA; PAR = 7.2 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 6. Peak-to-average power ratio as a function of average output power; typical values

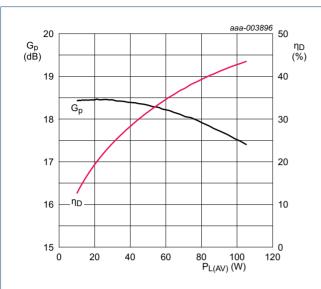


 V_{DS} = 28 V; I_{Dq} = 1600 mA; PAR = 7.2 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

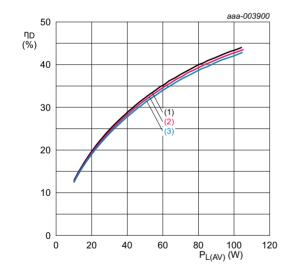
Adjacent power channel ratio (5 MHz) as a function of average output power; typical values

8.4.3 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 1600 mA; f = 1843 MHz; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

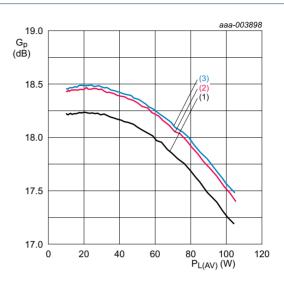
Fig 8. Power gain and drain efficiency as function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 1600 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

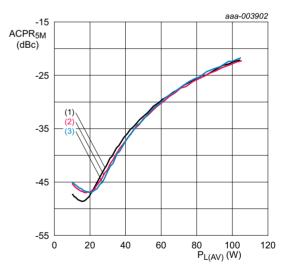
Fig 10. Drain efficiency as a function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 1600 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 9. Power gain as a function of average output power; typical values



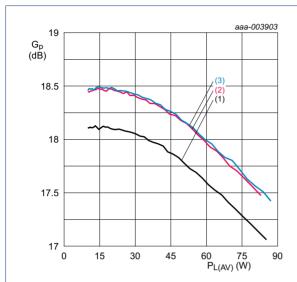
 V_{DS} = 28 V; I_{Dq} = 1600 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 11. Adjacent power channel ratio (5 MHz) as a function of average output power; typical values

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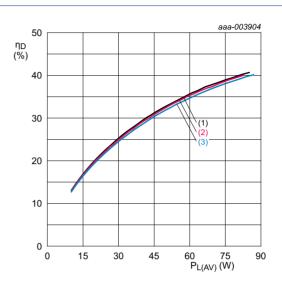
8.4.4 IS-95



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1600 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

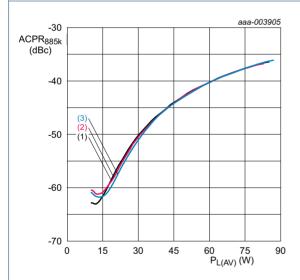
Fig 12. Power gain as a function of average output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1600 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

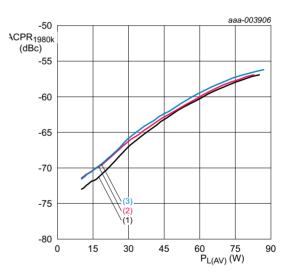
Fig 13. Drain efficiency as a function of average output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1600 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 14. Adjacent power channel ratio (885 kHz) as a function of average output power; typical values

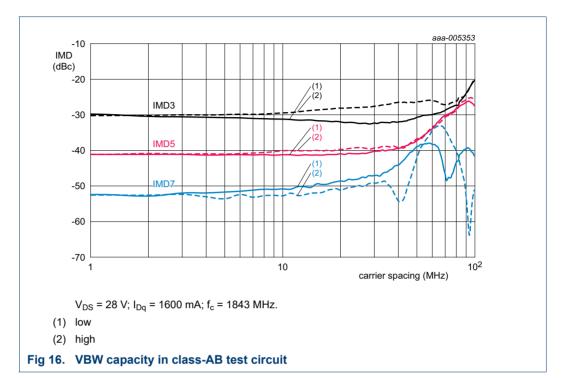


 $V_{DS} = 28 \text{ V}; I_{Dq} = 1600 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 15. Adjacent power channel ratio (1980 kHz) as a function of average output power; typical values

8.4.5 2-Tone VBW



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9. Package outline

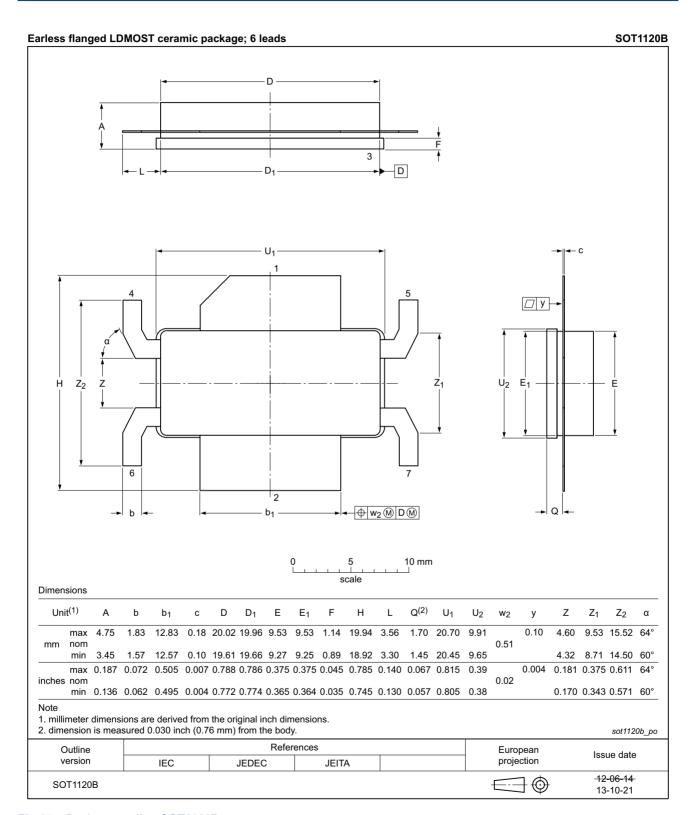


Fig 17. Package outline SOT1120B

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

11. Abbreviations

Table 11. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
MTTF	Mean Time To Failure
PAR	Peak-to-Average Ratio
VSWR	Voltage Standing Wave Ratio
VBW	Video BandWidth
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLF8G20LS-200V#5	20150901	Product data sheet		BLF8G20LS-200V v.4			
Modifications:		 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 					
	 Legal texts 	have been adapted to the	new company name w	here appropriate.			
BLF8G20LS-200V v.4	20131021	Product data sheet	-	BLF8G20LS-200V v.3			
BLF8G20LS-200V v.3	20130121	Product data sheet	-	BLF8G20LS-200V v.2			
BLF8G20LS-200V v.2	20121012	Product data sheet	-	BLF8G20LS-200V v.1			
BLF8G20LS-200V v.1	20120704	Objective data sheet	-	-			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Power LDMOS transistor

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BLF8G20LS-200V

Power LDMOS transistor

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